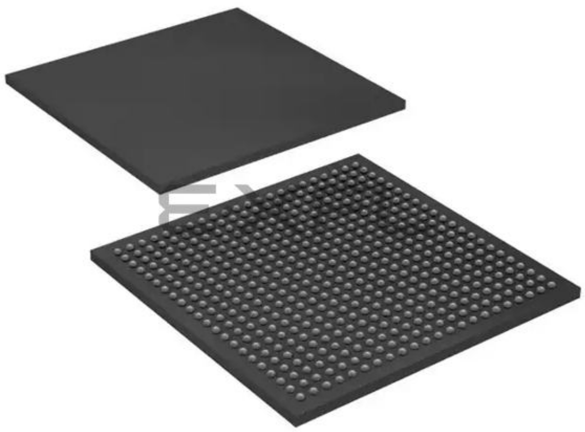

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Obsolete
Number of LABs/CLBs	1846
Number of Logic Elements/Cells	18460
Total RAM Bits	1669248
Number of I/O	361
Number of Gates	-
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-BBGA, FCBGA
Supplier Device Package	484-FBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep1s20f484i6n

Stratix devices are available in space-saving FineLine BGA® and ball-grid array (BGA) packages (see Tables 1–3 through 1–5). All Stratix devices support vertical migration within the same package (for example, you can migrate between the EP1S10, EP1S20, and EP1S25 devices in the 672-pin BGA package). Vertical migration means that you can migrate to devices whose dedicated pins, configuration pins, and power pins are the same for a given package across device densities. For I/O pin migration across densities, you must cross-reference the available I/O pins using the device pin-outs for all planned densities of a given package type to identify which I/O pins are migrational. The Quartus® II software can automatically cross reference and place all pins except differential pins for migration when given a device migration list. You must use the pin-outs for each device to verify the differential placement migration. A future version of the Quartus II software will support differential pin migration.

Table 1–3. Stratix Package Options & I/O Pin Counts

Device	672-Pin BGA	956-Pin BGA	484-Pin FineLine BGA	672-Pin FineLine BGA	780-Pin FineLine BGA	1,020-Pin FineLine BGA	1,508-Pin FineLine BGA
EP1S10	345		335	345	426		
EP1S20	426		361	426	586		
EP1S25	473			473	597	706	
EP1S30		683			597	726	
EP1S40		683			615	773	822
EP1S60		683				773	1,022
EP1S80		683				773	1,203

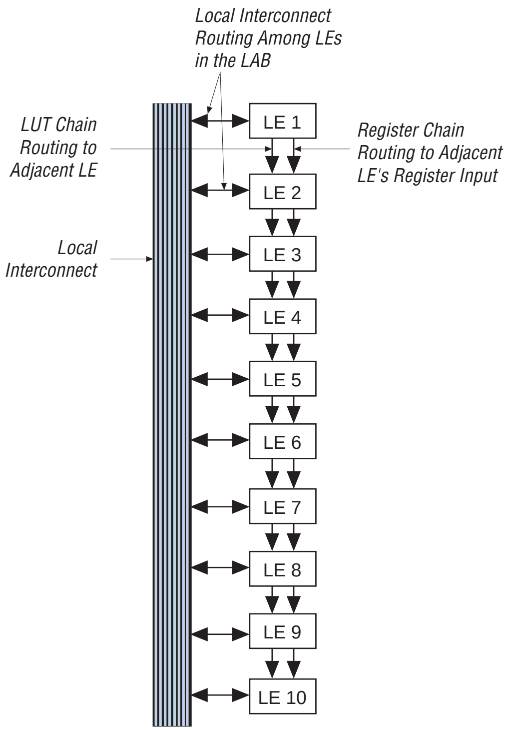
Note to Table 1–3:

(1) All I/O pin counts include 20 dedicated clock input pins (`clk[15..0]p`, `clk0n`, `clk2n`, `clk9n`, and `clk11n`) that can be used for data inputs.

Table 1–4. Stratix BGA Package Sizes

Dimension	672 Pin	956 Pin
Pitch (mm)	1.27	1.27
Area (mm^2)	1,225	1,600
Length × width (mm × mm)	35 × 35	40 × 40

Figure 2–10. LUT Chain & Register Chain Interconnects



The C4 interconnects span four LABs, M512, or M4K blocks up or down from a source LAB. Every LAB has its own set of C4 interconnects to drive either up or down. Figure 2–11 shows the C4 interconnect connections from an LAB in a column. The C4 interconnects can drive and be driven by all types of architecture blocks, including DSP blocks, TriMatrix memory blocks, and vertical IOEs. For LAB interconnection, a primary LAB or its LAB neighbor can drive a given C4 interconnect.
C4 interconnects can drive each other to extend their range as well as drive row interconnects for column-to-column connections.

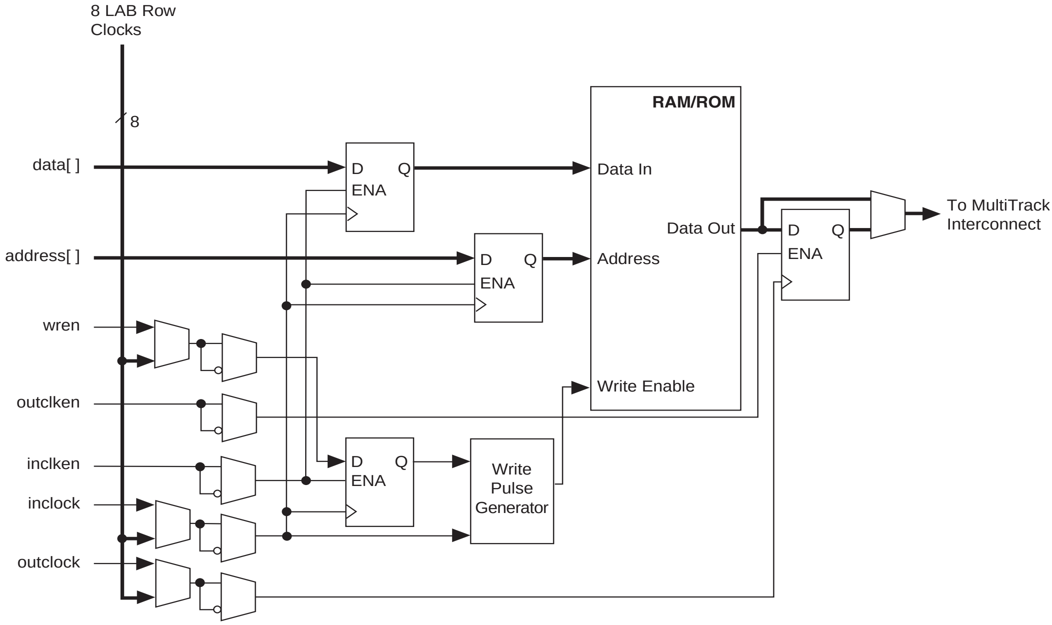
M512 RAM blocks can have different clocks on its inputs and outputs. The `wren`, `datain`, and write address registers are all clocked together from one of the two clocks feeding the block. The read address, `rden`, and output registers can be clocked by either of the two clocks driving the block. This allows the RAM block to operate in read/write or input/output clock modes. Only the output register can be bypassed. The eight `labclk` signals or local interconnect can drive the `inclock`, `outclock`, `wren`, `rden`, `inclr`, and `outclr` signals. Because of the advanced interconnect between the LAB and M512 RAM blocks, LEs can also control the `wren` and `rden` signals and the RAM clock, clock enable, and asynchronous clear signals. Figure 2–15 shows the M512 RAM block control signal generation logic.

The RAM blocks within Stratix devices have local interconnects to allow LEs and interconnects to drive into RAM blocks. The M512 RAM block local interconnect is driven by the R4, R8, C4, C8, and direct link interconnects from adjacent LABs. The M512 RAM blocks can communicate with LABs on either the left or right side through these row interconnects or with LAB columns on the left or right side with the column interconnects. Up to 10 direct link input connections to the M512 RAM block are possible from the left adjacent LABs and another 10 possible from the right adjacent LAB. M512 RAM outputs can also connect to left and right LABs through 10 direct link interconnects. The M512 RAM block has equal opportunity for access and performance to and from LABs on either its left or right side. Figure 2–16 shows the M512 RAM block to logic array interface.

Single-Port Mode

The memory blocks also support single-port mode, used when simultaneous reads and writes are not required. See Figure 2–28. A single block in a memory block can support up to two single-port mode RAM blocks in the M4K RAM blocks if each RAM block is less than or equal to 2K bits in size.

Figure 2–28. Single-Port Mode *Note (1)*



Note to Figure 2–28:

(1) Violating the setup or hold time on the address registers could corrupt the memory contents. This applies to both read and write operations.

Table 2–14 shows the summary of input register modes for the DSP block.

Table 2–14. Input Register Modes

Register Input Mode	9 × 9	18 × 18	36 × 36
Parallel input	✓	✓	✓
Shift register input	✓	✓	

Multiplier

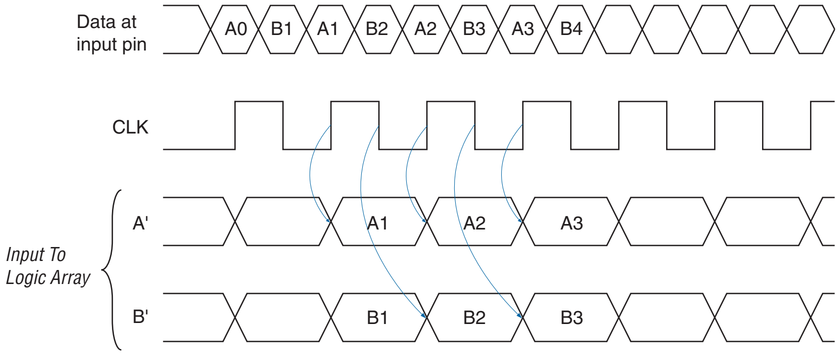
The multiplier supports 9 × 9-, 18 × 18-, or 36 × 36-bit multiplication. Each DSP block supports eight possible 9 × 9-bit or smaller multipliers. There are four multiplier blocks available for multipliers larger than 9 × 9 bits but smaller than 18 × 18 bits. There is one multiplier block available for multipliers larger than 18 × 18 bits but smaller than or equal to 36 × 36 bits. The ability to have several small multipliers is useful in applications such as video processing. Large multipliers greater than 18 × 18 bits are useful for applications such as the mantissa multiplication of a single-precision floating-point number.

The multiplier operands can be signed or unsigned numbers, where the result is signed if either input is signed as shown in Table 2–15. The `sign_a` and `sign_b` signals provide dynamic control of each operand's representation: a logic 1 indicates the operand is a signed number, a logic 0 indicates the operand is an unsigned number. These sign signals affect all multipliers and adders within a single DSP block and you can register them to match the data path pipeline. The multipliers are full precision (that is, 18 bits for the 18-bit multiply, 36-bits for the 36-bit multiply, and so on) regardless of whether `sign_a` or `sign_b` set the operands as signed or unsigned numbers.

Table 2–15. Multiplier Signed Representation

Data A	Data B	Result
Unsigned	Unsigned	Unsigned
Unsigned	Signed	Signed
Signed	Unsigned	Signed
Signed	Signed	Signed

Figure 2–66. Input Timing Diagram in DDR Mode



When using the IOE for DDR outputs, the two output registers are configured to clock two data paths from LEs on rising clock edges. These output registers are multiplexed by the clock to drive the output pin at a ×2 rate. One output register clocks the first bit out on the clock high time, while the other output register clocks the second bit out on the clock low time. Figure 2–67 shows the IOE configured for DDR output. Figure 2–68 shows the DDR output timing diagram.

Tables 2–25 and 2–26 show the performance specification for DDR SDRAM, RLDRAM II, QDR SRAM, QDRII SRAM, and ZBT SRAM interfaces in EP1S10 through EP1S40 devices and in EP1S60 and EP1S80 devices. The DDR SDRAM and QDR SRAM numbers in Table 2–25 have been verified with hardware characterization with third-party DDR SDRAM and QDR SRAM devices over temperature and voltage extremes.

Table 2–25. External RAM Support in EP1S10 through EP1S40 Devices

DDR Memory Type	I/O Standard	Maximum Clock Rate (MHz)						
		-5 Speed Grade	-6 Speed Grade		-7 Speed Grade		-8 Speed Grade	
		Flip-Chip	Flip-Chip	Wire-Bond	Flip-Chip	Wire-Bond	Flip-Chip	Wire-Bond
DDR SDRAM *(1)*, *(2)*	SSTL-2	200	167	133	133	100	100	100
DDR SDRAM - side banks *(2)*, *(3)*, *(4)*	SSTL-2	150	133	110	133	100	100	100
RLDRAM II *(4)*	1.8-V HSTL	200	*(5)*	*(5)*	*(5)*	*(5)*	*(5)*	*(5)*
QDR SRAM *(6)*	1.5-V HSTL	167	167	133	133	100	100	100
QDRII SRAM *(6)*	1.5-V HSTL	200	167	133	133	100	100	100
ZBT SRAM *(7)*	LVTTL	200	200	200	167	167	133	133

Notes to Table 2–25:

(1) These maximum clock rates apply if the Stratix device uses DQS phase-shift circuitry to interface with DDR SDRAM. DQS phase-shift circuitry is only available in the top and bottom I/O banks (I/O banks 3, 4, 7, and 8).

(2) For more information on DDR SDRAM, see *AN 342: Interfacing DDR SDRAM with Stratix & Stratix GX Devices.*

(3) DDR SDRAM is supported on the Stratix device side I/O banks (I/O banks 1, 2, 5, and 6) without dedicated DQS phase-shift circuitry. The read DQS signal is ignored in this mode.

(4) These performance specifications are preliminary.

(5) This device does not support RLDRAM II.

(6) For more information on QDR or QDRII SRAM, see *AN 349: QDR SRAM Controller Reference Design for Stratix & Stratix GX Devices*.

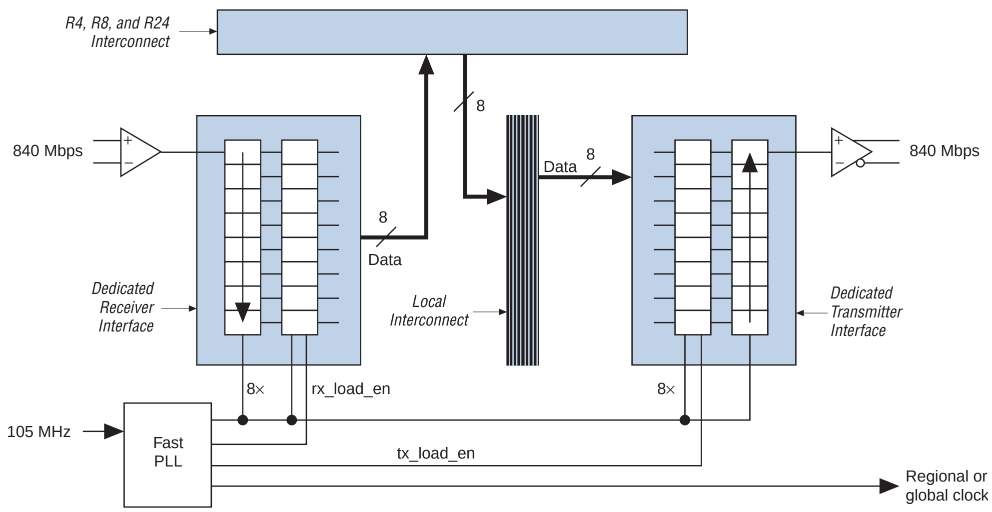
(7) For more information on ZBT SRAM, see *AN 329: ZBT SRAM Controller Reference Design for Stratix & Stratix GX Devices*.

- RapidIO
- HyperTransport

Dedicated Circuitry

Stratix devices support source-synchronous interfacing with LVDS, LVPECL, 3.3-V PCML, or HyperTransport signaling at up to 840 Mbps. Stratix devices can transmit or receive serial channels along with a low-speed or high-speed clock. The receiving device PLL multiplies the clock by a integer factor W (W = 1 through 32). For example, a HyperTransport application where the data rate is 800 Mbps and the clock rate is 400 MHz would require that W be set to 2. The SERDES factor J determines the parallel data width to deserialize from receivers or to serialize for transmitters. The SERDES factor J can be set to 4, 7, 8, or 10 and does not have to equal the PLL clock-multiplication W value. For a J factor of 1, the Stratix device bypasses the SERDES block. For a J factor of 2, the Stratix device bypasses the SERDES block, and the DDR input and output registers are used in the IOE. See Figure 2–73.

Figure 2–73. High-Speed Differential I/O Receiver / Transmitter Interface Example



An external pin or global or regional clock can drive the fast PLLs, which can output up to three clocks: two multiplied high-speed differential I/O clocks to drive the SERDES block and/or external pin, and a low-speed clock to drive the logic array.

Table 4–45. IOE Internal TSU Microparameter by Device Density (Part 2 of 2)										
Device	**Symbol**	**-5**		**-6**		**-7**		**-8**		**Unit**
		Min	**Max**	**Min**	**Max**	**Min**	**Max**	**Min**	**Max**	
EP1S40	t_{SU_R}	76		80		80		80		ps
	t_{SU_C}	376		380		380		380		ps
EP1S60	t_{SU_R}	276		280		280		280		ps
	t_{SU_C}	276		280		280		280		ps
EP1S80	t_{SU_R}	426		430		430		430		ps
	t_{SU_C}	76		80		80		80		ps

Table 4–46. IOE Internal Timing Microparameters									
Symbol	**-5**		**-6**		**-7**		**-8**		**Unit**
	Min	**Max**	**Min**	**Max**	**Min**	**Max**	**Min**	**Max**	
t_H	68		71		82		96		ps
t_{CO_R}		171		179		206		242	ps
t_{CO_C}		171		179		206		242	ps
$t_{PIN2COMBOUT\_R}$		1,234		1,295		1,490		1,753	ps
$t_{PIN2COMBOUT\_C}$		1,087		1,141		1,312		1,544	ps
$t_{COMBIN2PIN\_R}$		3,894		4,089		4,089		4,089	ps
$t_{COMBIN2PIN\_C}$		4,299		4,494		4,494		4,494	ps
t_{CLR}	276		289		333		392		ps
t_{PRE}	260		273		313		369		ps
t_{CLKHL}	1,000		1,111		1,190		1,400		ps

Table 4–47. DSP Block Internal Timing Microparameters (Part 1 of 2)									
Symbol	**-5**		**-6**		**-7**		**-8**		**Unit**
	Min	**Max**	**Min**	**Max**	**Min**	**Max**	**Min**	**Max**	
t_{SU}	0		0		0		0		ps
t_H	67		75		86		101		ps
t_{CO}		142		158		181		214	ps
$t_{INREG2PIPE9}$		2,613		2,982		3,429		4,035	ps
$t_{INREG2PIPE18}$		3,390		3,993		4,591		5,402	ps

Table 4–53. Stratix Regional Clock External I/O Timing Parameters (Part 2 of 2) Notes (1), (2)	
Symbol	**Parameter**
t_{XZPLL}	Synchronous IOE output enable register to output pin disable delay using regional clock fed by Enhanced PLL with default phase setting
t_{ZXPLL}	Synchronous IOE output enable register to output pin enable delay using regional clock fed by Enhanced PLL with default phase setting

Notes to Table 4–53:
(1) These timing parameters are sample-tested only.
(2) These timing parameters are for column and row IOE pins. You should use the Quartus II software to verify the external timing for any pin.

Table 4–54 shows the external I/O timing parameters when using global clock networks.

Table 4–54. Stratix Global Clock External I/O Timing Parameters Notes (1), (2)	
Symbol	**Parameter**
t_{INSU}	Setup time for input or bidirectional pin using IOE input register with global clock fed by `CLK` pin
t_{INH}	Hold time for input or bidirectional pin using IOE input register with global clock fed by `CLK` pin
t_{OUTCO}	Clock-to-output delay output or bidirectional pin using IOE output register with global clock fed by `CLK` pin
$t_{INSUPLL}$	Setup time for input or bidirectional pin using IOE input register with global clock fed by Enhanced PLL with default phase setting
t_{INHPLL}	Hold time for input or bidirectional pin using IOE input register with global clock fed by Enhanced PLL with default phase setting
$t_{OUTCOPLL}$	Clock-to-output delay output or bidirectional pin using IOE output register with global clock Enhanced PLL with default phase setting
t_{XZPLL}	Synchronous IOE output enable register to output pin disable delay using global clock fed by Enhanced PLL with default phase setting
t_{ZXPLL}	Synchronous IOE output enable register to output pin enable delay using global clock fed by Enhanced PLL with default phase setting

Notes to Table 4–54:
(1) These timing parameters are sample-tested only.
(2) These timing parameters are for column and row IOE pins. You should use the Quartus II software to verify the external timing for any pin.

Table 4–83. EP1S40 External I/O Timing on Row Pins Using Regional Clock Networks									
Parameter	-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		-8 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.349		2.526		2.898		2.952		ns
t_{INH}	0.000		0.000		0.000		0.000		ns
t_{OUTCO}	2.725	5.381	2.725	5.784	2.725	6.290	2.725	7.426	ns
t_{XZ}	2.752	5.435	2.752	5.840	2.752	6.358	2.936	7.508	ns
t_{ZX}	2.752	5.435	2.752	5.840	2.752	6.358	2.936	7.508	ns
$t_{INSUPLL}$	1.328		1.322		1.605		1.883		ns
t_{INHPLL}	0.000		0.000		0.000		0.000		ns
$t_{OUTCOPLL}$	1.169	2.502	1.169	2.698	1.169	2.650	1.169	2.691	ns
t_{XZPLL}	1.196	2.556	1.196	2.754	1.196	2.718	1.196	2.773	ns
t_{ZXPLL}	1.196	2.556	1.196	2.754	1.196	2.718	1.196	2.773	ns

Table 4–84. EP1S40 External I/O Timing on Row Pins Using Global Clock Networks									
Parameter	-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		-8 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.020		2.171		2.491		2.898		ns
t_{INH}	0.000		0.000		0.000		0.000		ns
t_{OUTCO}	2.912	5.710	2.912	6.139	2.912	6.697	2.931	7.480	ns
t_{XZ}	2.939	5.764	2.939	6.195	2.939	6.765	2.958	7.562	ns
t_{ZX}	2.939	5.764	2.939	6.195	2.939	6.765	2.958	7.562	ns
$t_{INSUPLL}$	1.370		1.368		1.654		1.881		ns
t_{INHPLL}	0.000		0.000		0.000		0.000		ns
$t_{OUTCOPLL}$	1.144	2.460	1.144	2.652	1.144	2.601	1.170	2.693	ns
t_{XZPLL}	1.171	2.514	1.171	2.708	1.171	2.669	1.197	2.775	ns
t_{ZXPLL}	1.171	2.514	1.171	2.708	1.171	2.669	1.197	2.775	ns

Skew on Input Pins

Table 4–99 shows the package skews that were considered to get the worst case I/O skew value. You can use these values, for example, when calculating the timing budget on the input (read) side of a memory interface.

Table 4–99. Package Skew on Input Pins

Package Parameter	Worst-Case Skew (ps)
Pins in the same I/O bank	50
Pins in top/bottom (vertical I/O) banks	50
Pins in left/right side (horizontal I/O) banks	50
Pins across the entire device	100

PLL Counter & Clock Network Skews

Table 4–100 shows the clock skews between different clock outputs from the Stratix device PLL.

Table 4–100. PLL Counter & Clock Network Skews

Parameter	Worst-Case Skew (ps)
Clock skew between two external clock outputs driven by the same counter	100
Clock skew between two external clock outputs driven by the different counters with the same settings	150
Dual-purpose PLL dedicated clock output used as I/O pin vs. regular I/O pin	270 *(1)*
Clock skew between any two outputs of the PLL that drive global clock networks	150

Note to Table 4–100:

(1) The Quartus II software models 270 ps of delay on the PLL dedicated clock output (`PLL6_OUT[3..0]p/n` and `PLL5_OUT[3..0]p/n`) pins both when used as clocks and when used as I/O pins.

I/O Timing Measurement Methodology

Different I/O standards require different baseline loading techniques for reporting timing delays. Altera characterizes timing delays with the required termination and loading for each I/O standard. The timing information is specified from the input clock pin up to the output pin of

Tables 4–109 and 4–110 show the adder delays for the column and row IOE programmable delays. These delays are controlled with the Quartus II software logic options listed in the Parameter column.

Table 4–109. Stratix IOE Programmable Delays on Column Pins Note (1)										
Parameter	**Setting**	**-5 Speed Grade**		**-6 Speed Grade**		**-7 Speed Grade**		**-8 Speed Grade**		**Unit**
		Min	**Max**	**Min**	**Max**	**Min**	**Max**	**Min**	**Max**	
Decrease input delay to internal cells	Off		3,970		4,367		5,022		5,908	ps
	Small		3,390		3,729		4,288		5,045	ps
	Medium		2,810		3,091		3,554		4,181	ps
	Large		224		235		270		318	ps
	On		224		235		270		318	ps
Decrease input delay to input register	Off		3,900		4,290		4,933		5,804	ps
	On		0		0		0		0	ps
Decrease input delay to output register	Off		1,240		1,364		1,568		1,845	ps
	On		0		0		0		0	ps
Increase delay to output pin	Off		0		0		0		0	ps
	On		397		417		417		417	ps
Increase delay to output enable pin	Off		0		0		0		0	ps
	On		338		372		427		503	ps
Increase output clock enable delay	Off		0		0		0		0	ps
	Small		540		594		683		804	ps
	Large		1,016		1,118		1,285		1,512	ps
	On		1,016		1,118		1,285		1,512	ps
Increase input clock enable delay	Off		0		0		0		0	ps
	Small		540		594		683		804	ps
	Large		1,016		1,118		1,285		1,512	ps
	On		1,016		1,118		1,285		1,512	ps
Increase output enable clock enable delay	Off		0		0		0		0	ps
	Small		540		594		683		804	ps
	Large		1,016		1,118		1,285		1,512	ps
	On		1,016		1,118		1,285		1,512	ps
Increase t_{ZX} delay to output pin	Off		0		0		0		0	ps
	On		2,199		2,309		2,309		2,309	ps

Table 4–117. Stratix Maximum Input Clock Rate for CLK[7..4] & CLK[15..12] Pins in Wire-Bond Packages (Part 2 of 2)

I/O Standard	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit
GTL+	250	200	200	MHz
SSTL-3 Class I	300	250	250	MHz
SSTL-3 Class II	300	250	250	MHz
SSTL-2 Class I	300	250	250	MHz
SSTL-2 Class II	300	250	250	MHz
SSTL-18 Class I	300	250	250	MHz
SSTL-18 Class II	300	250	250	MHz
1.5-V HSTL Class I	300	180	180	MHz
1.5-V HSTL Class II	300	180	180	MHz
1.8-V HSTL Class I	300	180	180	MHz
1.8-V HSTL Class II	300	180	180	MHz
3.3-V PCI	422	390	390	MHz
3.3-V PCI-X 1.0	422	390	390	MHz
Compact PCI	422	390	390	MHz
AGP 1×	422	390	390	MHz
AGP 2×	422	390	390	MHz
CTT	250	180	180	MHz
Differential 1.5-V HSTL C1	300	180	180	MHz
LVPECL *(1)*	422	400	400	MHz
PCML *(1)*	215	200	200	MHz
LVDS *(1)*	422	400	400	MHz
HyperTransport technology *(1)*	422	400	400	MHz

Table 4–118. Stratix Maximum Input Clock Rate for CLK[0, 2, 9, 11] Pins & FPLL[10..7]CLK Pins in Wire-Bond Packages (Part 1 of 2)

I/O Standard	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit
LVTTL	422	390	390	MHz
2.5 V	422	390	390	MHz
1.8 V	422	390	390	MHz
1.5 V	422	390	390	MHz

Table 4–122. Stratix Maximum Output Clock Rate for PLL[5, 6, 11, 12] Pins in Wire-Bond Packages (Part 2 of 2)

I/O Standard	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit
LVDS *(2)*	311	275	275	MHz
HyperTransport technology *(2)*	311	275	275	MHz

Table 4–123. Stratix Maximum Output Clock Rate (Using I/O Pins) for PLL[1, 2, 3, 4] Pins in Wire-Bond Packages (Part 1 of 2)

I/O Standard	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit
LVTTL	200	175	175	MHz
2.5 V	200	175	175	MHz
1.8 V	200	175	175	MHz
1.5 V	200	175	175	MHz
LVCMOS	200	175	175	MHz
GTL	125	100	100	MHz
GTL+	125	100	100	MHz
SSTL-3 Class I	110	90	90	MHz
SSTL-3 Class II	150	133	133	MHz
SSTL-2 Class I	90	80	80	MHz
SSTL-2 Class II	110	100	100	MHz
SSTL-18 Class I	110	100	100	MHz
SSTL-18 Class II	110	100	100	MHz
1.5-V HSTL Class I	225	200	200	MHz
1.5-V HSTL Class II	200	167	167	MHz
1.8-V HSTL Class I	225	200	200	MHz
1.8-V HSTL Class II	200	167	167	MHz
3.3-V PCI	200	175	175	MHz
3.3-V PCI-X 1.0	200	175	175	MHz
Compact PCI	200	175	175	MHz
AGP 1×	200	175	175	MHz
AGP 2×	200	175	175	MHz
CTT	125	100	100	MHz
LVPECL *(2)*	311	270	270	MHz
PCML *(2)*	400	311	311	MHz

Table 4–125. High-Speed I/O Specifications for Flip-Chip Packages (Part 2 of 4) Notes (1), (2)

Symbol	Conditions	-5 Speed Grade			-6 Speed Grade			-7 Speed Grade			-8 Speed Grade			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f_{HSCLK} (Clock frequency) (PCML) $f_{HSCLK} = f_{HSDR}$ / W	*W* = 4 to 30 (Serdes used)	10		100	10		100	10		77.75	10		77.75	MHz
	W = 2 (Serdes bypass)	50		200	50		200	50		150	50		150	MHz
	W = 2 (Serdes used)	150		200	150		200	150		155.5	150		155.5	MHz
	W = 1 (Serdes bypass)	100		250	100		250	100		200	100		200	MHz
	W = 1 (Serdes used)	300		400	300		400	300		311	300		311	MHz
f_{HSDR} Device operation (PCML)	*J* = 10	300		400	300		400	300		311	300		311	Mbps
	J = 8	300		400	300		400	300		311	300		311	Mbps
	J = 7	300		400	300		400	300		311	300		311	Mbps
	J = 4	300		400	300		400	300		311	300		311	Mbps
	J = 2	100		400	100		400	100		300	100		300	Mbps
	J = 1	100		250	100		250	100		200	100		200	Mbps
TCCS	All			200			200			300			300	ps

Table 4–125. High-Speed I/O Specifications for Flip-Chip Packages (Part 4 of 4) Notes (1), (2)														
Symbol	Conditions	-5 Speed Grade			-6 Speed Grade			-7 Speed Grade			-8 Speed Grade			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
t_{DUTY}	LVDS (*J* = 2 through 10)	47.5	50	52.5	47.5	50	52.5	47.5	50	52.5	47.5	50	52.5	%
	LVDS (*J* =1) and LVPECL, PCML, HyperTransport technology	45	50	55	45	50	55	45	50	55	45	50	55	%
t_{LOCK}	All			100			100			100			100	µs

Notes to Table 4–125:

(1) When J = 4, 7, 8, and 10, the SERDES block is used.

(2) When J = 2 or J = 1, the SERDES is bypassed.

Table 4–126. High-Speed I/O Specifications for Wire-Bond Packages (Part 1 of 2)

Symbol	Conditions	-6 Speed Grade			-7 Speed Grade			-8 Speed Grade			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f_{HSCLK} (Clock frequency) (LVDS,LVPECL, HyperTransport technology) $f_{HSCLK} = f_{HSDR} / W$	*W* = 4 to 30 (Serdes used)	10		156	10		115.5	10		115.5	MHz
	W = 2 (Serdes bypass)	50		231	50		231	50		231	MHz
	W = 2 (Serdes used)	150		312	150		231	150		231	MHz
	W = 1 (Serdes bypass)	100		311	100		270	100		270	MHz
	W = 1 (Serdes used)	300		624	300		462	300		462	MHz
f_{HSDR} Device operation, (LVDS,LVPECL, HyperTransport technology)	J = 10	300		624	300		462	300		462	Mbps
	J = 8	300		624	300		462	300		462	Mbps
	J = 7	300		624	300		462	300		462	Mbps
	J = 4	300		624	300		462	300		462	Mbps
	J = 2	100		462	100		462	100		462	Mbps
	J = 1 (LVDS and LVPECL only)	100		311	100		270	100		270	Mbps
f_{HSCLK} (Clock frequency) (PCML) $f_{HSCLK} = f_{HSDR} / W$	*W* = 4 to 30 (Serdes used)	10		77.75							MHz
	W = 2 (Serdes bypass)	50		150	50		77.5	50		77.5	MHz
	W = 2 (Serdes used)	150		155.5							MHz
	W = 1 (Serdes bypass)	100		200	100		155	100		155	MHz
	W = 1 (Serdes used)	300		311							MHz
Device operation, f_{HSDR} (PCML)	J = 10	300		311							Mbps
	J = 8	300		311							Mbps
	J = 7	300		311							Mbps
	J = 4	300		311							Mbps
	J = 2	100		300	100		155	100		155	Mbps
	J = 1	100		200	100		155	100		155	Mbps
TCCS	All			400			400			400	ps

PLL Specifications

Tables 4–127 through 4–129 describe the Stratix device enhanced PLL specifications.

Table 4–127. Enhanced PLL Specifications for -5 Speed Grades (Part 1 of 2)

Symbol	Parameter	Min	Typ	Max	Unit
f_{IN}	Input clock frequency	3 *(1)*, *(2)*		684	MHz
f_{INPFD}	Input frequency to PFD	3		420	MHz
f_{INDUTY}	Input clock duty cycle	40		60	%
$f_{EINDUTY}$	External feedback clock input duty cycle	40		60	%
$t_{INJITTER}$	Input clock period jitter			±200 *(3)*	ps
$t_{EINJITTER}$	External feedback clock period jitter			±200 *(3)*	ps
t_{FCOMP}	External feedback clock compensation time *(4)*			6	ns
f_{OUT}	Output frequency for internal global or regional clock	0.3		500	MHz
f_{OUT_EXT}	Output frequency for external clock *(3)*	0.3		526	MHz
$t_{OUTDUTY}$	Duty cycle for external clock output (when set to 50%)	45		55	%
t_{JITTER}	Period jitter for external clock output *(6)*			±100 ps for >200-MHz `outclk` ±20 mUI for <200-MHz `outclk`	ps or mUI
$t_{CONFIG5,6}$	Time required to reconfigure the scan chains for PLLs 5 and 6			$289/f_{SCANCLK}$	
$t_{CONFIG11,12}$	Time required to reconfigure the scan chains for PLLs 11 and 12			$193/f_{SCANCLK}$	
$t_{SCANCLK}$	`scanclk` frequency *(5)*			22	MHz
t_{DLOCK}	Time required to lock dynamically (after switchover or reconfiguring any non-post-scale counters/delays) *(7)*			100	µs
t_{LOCK}	Time required to lock from end of device configuration	10		400	µs
f_{VCO}	PLL internal VCO operating range	300		800 *(8)*	MHz
t_{LSKEW}	Clock skew between two external clock outputs driven by the same counter		±50		ps

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